# NSN 5961-00-836-3073

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Inclosure Material:

Metal

**Overall Length:** 

0.450 inches

## **Overall Diameter:**

0.875 inches

## Mounting Facility Quantity:

2

#### Internal Configuration:

Junction contact

### Electrode Internally-electrically Connected To Case:

Collector

Internal Junction Configuration:

Npn

#### **Mounting Method:**

Unthreaded hole

## Features Provided:

Hermetically sealed case

#### Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

100.0 collector to base voltage/static/emitter open and 60.0 collector to emitter voltage/static/base open and 70.0 collector to emitter

reverse voltage and 7.0 emitter to base voltage, static, collector open

#### **Current Rating Per Characteristic:**

15.00 amperes source cutoff current

#### Power Rating Per Characteristic:

115.0 watts small-signal input power, common-collector absolute

#### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Terminal Type And Quantity:**

2 uninsulated wire lead and 1 case

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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